

BC857BTT1, BC857CTT1

Preferred Devices

General Purpose Transistor

PNP Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-416/SC-75 which is designed for low power surface mount applications.

Features

- Pb-Free Package is Available*

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

| Rating | Symbol | Max | Unit |
|--------------------------------|-----------|------|------|
| Collector-Emitter Voltage | V_{CEO} | -45 | V |
| Collector-Base Voltage | V_{CBO} | -50 | V |
| Emitter-Base Voltage | V_{EBO} | -5.0 | V |
| Collector Current - Continuous | I_C | -100 | mAdc |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

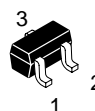
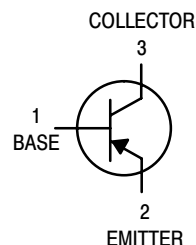
| Characteristic | Symbol | Max | Unit |
|--|-----------------|----------------|---------------------------|
| Total Device Dissipation, FR-4 Board (Note 1) $T_A = 25^\circ\text{C}$ Derated above 25°C | P_D | 200 | mW |
| Thermal Resistance, Junction-to-Ambient (Note 1) | $R_{\theta JA}$ | 600 | $^\circ\text{C}/\text{W}$ |
| Total Device Dissipation, FR-4 Board (Note 2) $T_A = 25^\circ\text{C}$ Derated above 25°C | P_D | 300 | mW |
| Thermal Resistance, Junction-to-Ambient (Note 2) | $R_{\theta JA}$ | 400 | $^\circ\text{C}/\text{W}$ |
| Junction and Storage Temperature Range | T_J, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

- FR-4 @ min pad.
- FR-4 @ 1.0×1.0 in pad.



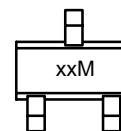
ON Semiconductor®

<http://onsemi.com>



CASE 463
SOT-416
STYLE 1

MARKING DIAGRAM



xx = Device Code
M = Date Code

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BC857BTT1, BC857CTT1

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|---|----------------------|------------|--------------|----------------|----------|
| OFF CHARACTERISTICS | | | | | |
| Collector–Emitter Breakdown Voltage (I _C = –10 mA) BC857 Series | V _{(BR)CEO} | –45 | – | – | V |
| Collector–Emitter Breakdown Voltage (I _C = –10 μA, V _{EB} = 0) BC857B Only | V _{(BR)CES} | –50 | – | – | V |
| Collector–Base Breakdown Voltage (I _C = –10 μA) BC857 Series | V _{(BR)CBO} | –50 | – | – | V |
| Emitter–Base Breakdown Voltage (I _E = –1.0 μA) BC857 Series | V _{(BR)EBO} | –5.0 | – | – | V |
| Collector Cutoff Current (V _{CB} = –30 V) (V _{CB} = –30 V, T _A = 150°C) | I _{CBO} | – | – | –15 –4.0 | nA μA |
| ON CHARACTERISTICS | | | | | |
| DC Current Gain (I _C = –10 μA, V _{CE} = –5.0 V) BC857B BC857C | h _{FE} | – – | 150 270 | – – | – |
| (I _C = –2.0 mA, V _{CE} = –5.0 V) BC857B BC857C | | 220 420 | 290 520 | 475 800 | |
| Collector–Emitter Saturation Voltage (I _C = –10 mA, I _B = –0.5 mA) (I _C = –100 mA, I _B = –5.0 mA) | V _{CE(sat)} | – – | – – | –0.3 –0.65 | V |
| Base–Emitter Saturation Voltage (I _C = –10 mA, I _B = –0.5 mA) (I _C = –100 mA, I _B = –5.0 mA) | V _{BE(sat)} | – – | –0.7 –0.9 | – – | V |
| Base–Emitter On Voltage (I _C = –2.0 mA, V _{CE} = –5.0 V) (I _C = –10 mA, V _{CE} = –5.0 V) | V _{BE(on)} | –0.6 – | – – | –0.75 –0.82 | V |
| SMALL–SIGNAL CHARACTERISTICS | | | | | |
| Current–Gain – Bandwidth Product (I _C = –10 mA, V _{CE} = –5.0 Vdc, f = 100 MHz) | f _T | 100 | – | – | MHz |
| Output Capacitance (V _{CB} = –10 V, f = 1.0 MHz) | C _{ob} | – | – | 4.5 | pF |
| Noise Figure (I _C = –0.2 mA, V _{CE} = –5.0 Vdc, R _S = 2.0 kΩ, f = 1.0 kHz, BW = 200 Hz) | NF | – | – | 10 | dB |

BC857BTT1, BC857CTT1

TYPICAL CHARACTERISTICS

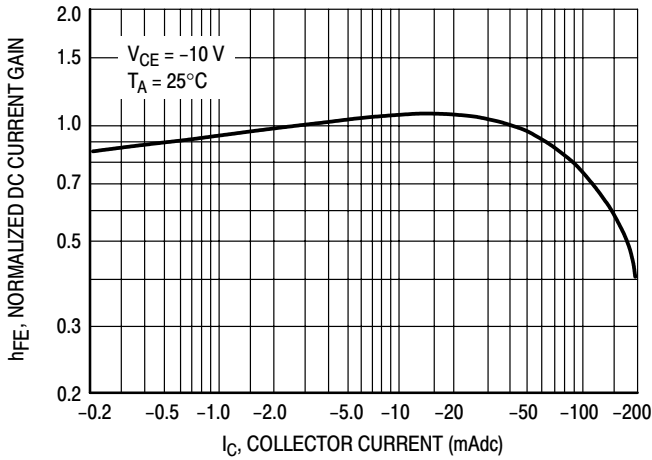


Figure 1. Normalized DC Current Gain

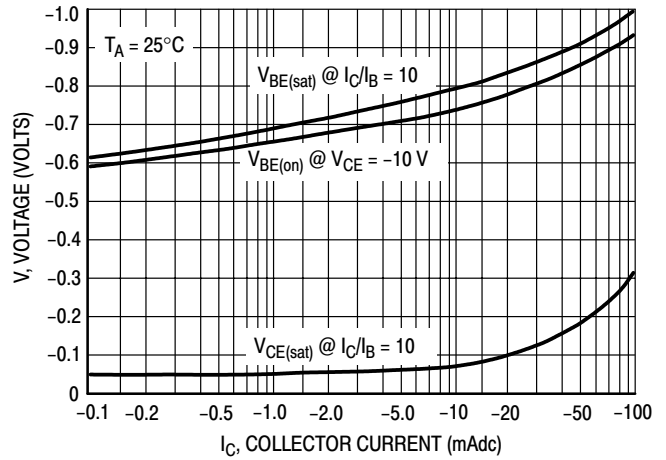


Figure 2. "Saturation" and "On" Voltages

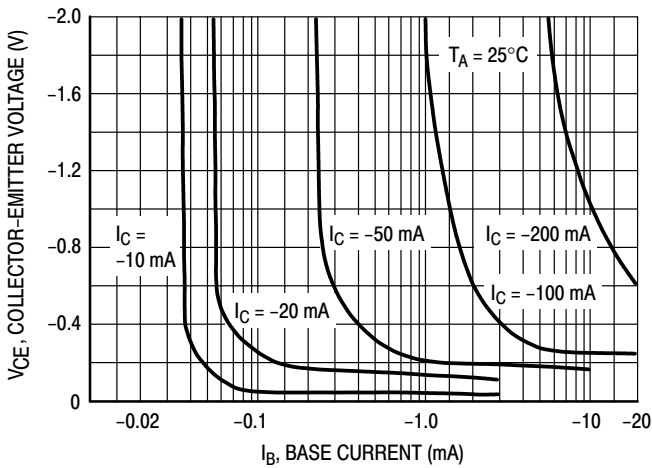


Figure 3. Collector Saturation Region

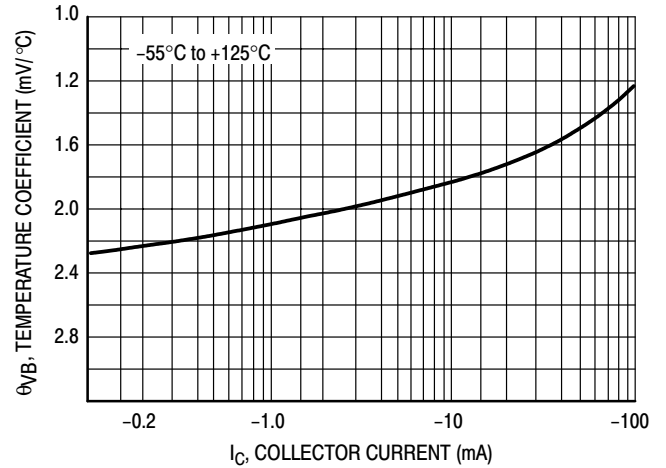


Figure 4. Base-Emitter Temperature Coefficient

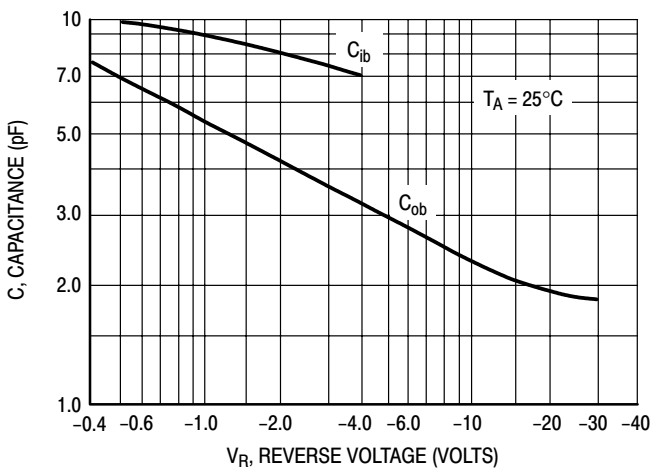


Figure 5. Capacitances

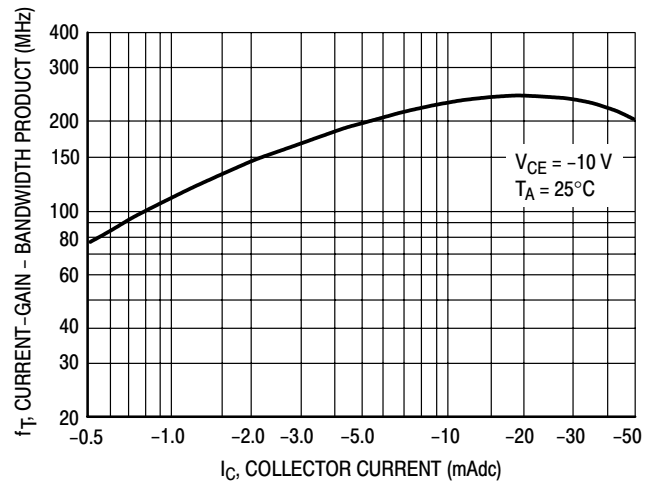


Figure 6. Current-Gain - Bandwidth Product

BC857BTT1, BC857CTT1

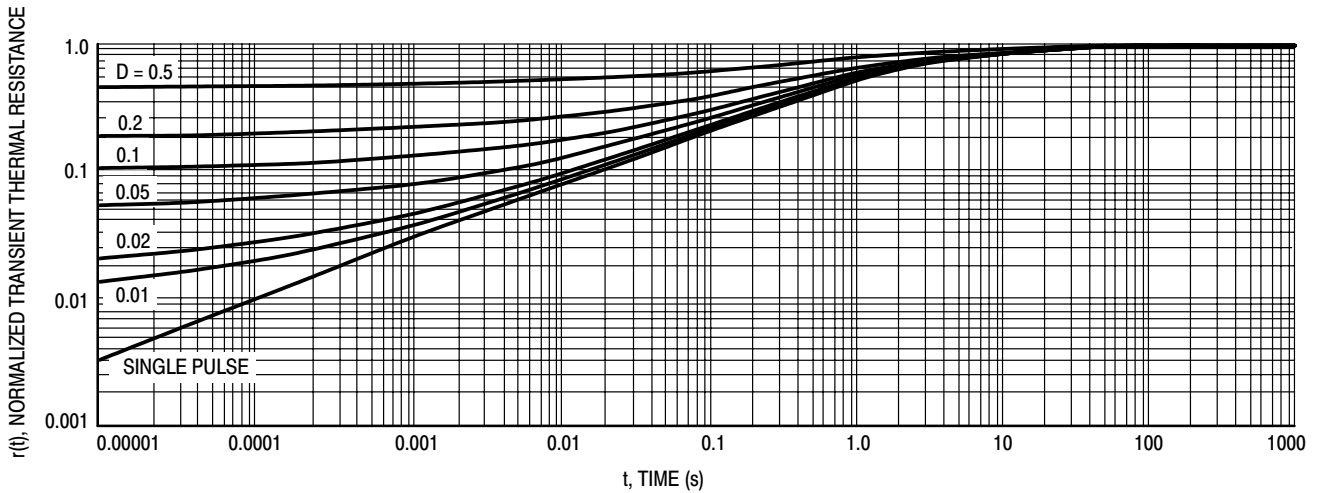


Figure 7. Thermal Response

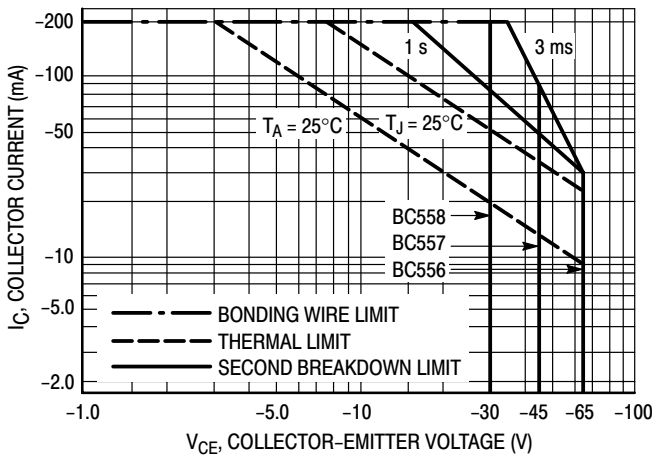


Figure 8. Active Region Safe Operating Area

The safe operating area curves indicate I_C - V_{CE} limits of the transistor that must be observed for reliable operation. Collector load lines for specific circuits must fall below the limits indicated by the applicable curve.

The data of Figure 8 is based upon $T_{J(pk)} = 150^\circ\text{C}$; T_C or T_A is variable depending upon conditions. Pulse curves are valid for duty cycles to 10% provided $T_{J(pk)} \leq 150^\circ\text{C}$. $T_{J(pk)}$ may be calculated from the data in Figure 7. At high case or ambient temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by the secondary breakdown.

ORDERING INFORMATION

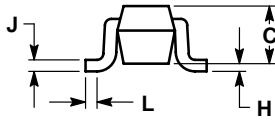
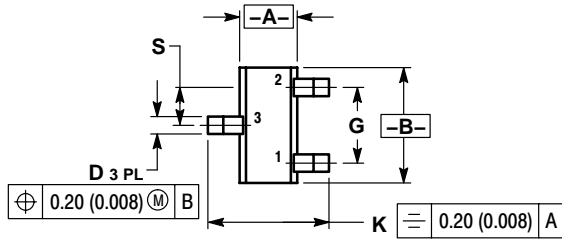
| Device | Marking | Package | Shipping† |
|------------|---------|-------------------|---------------------|
| BC857BTT1 | 3F | SOT-416 | 3,000 / Tape & Reel |
| BC857BTT1G | 3F | SOT-416 (PB-Free) | |
| BC857CTT1 | 3G | SOT-416 | 3,000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BC857BTT1, BC857CTT1

PACKAGE DIMENSIONS

SOT-416 (SC-75)
CASE 463-01
ISSUE C



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.

| DIM | MILLIMETERS | | INCHES | |
|-----|-------------|------|-----------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.70 | 0.90 | 0.028 | 0.035 |
| B | 1.40 | 1.80 | 0.055 | 0.071 |
| C | 0.60 | 0.90 | 0.024 | 0.035 |
| D | 0.15 | 0.30 | 0.006 | 0.012 |
| G | 1.00 BSC | | 0.039 BSC | |
| H | --- | 0.10 | --- | 0.004 |
| J | 0.10 | 0.25 | 0.004 | 0.010 |
| K | 1.45 | 1.75 | 0.057 | 0.069 |
| L | 0.10 | 0.20 | 0.004 | 0.008 |
| S | 0.50 BSC | | 0.020 BSC | |

BC857BTT1, BC857CTT1

ON Semiconductor and  are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
P.O. Box 61312, Phoenix, Arizona 85082-1312 USA
Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada
Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center
2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051
Phone: 81-3-5773-3850

ON Semiconductor Website: <http://onsemi.com>

Order Literature: <http://www.onsemi.com/litorder>

For additional information, please contact your
local Sales Representative.